Transistors C8550

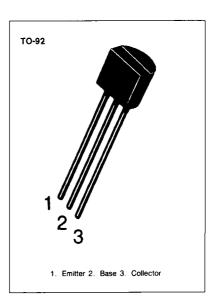


2W OUTPUT AMPLIFIER OF PORTABLE RADIOS IN CLASS B PUSH-PULL OPERATION.

- Collector Current Ic = -1.5A
- Collector Dissipation $P_c = 2W$ (T_c = 25°C)

ABSOLUTE MAXIMUM RATINGS (T_a=25°C)

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	V _{CBO}	-40	v
Collector-Emitter Voltage	V _{CEO}	-25	v
Emitter-Base Voltage	VEBO	-6	v
Collector Current	Ic	-1.5	A
Collector Dissipation	Pc	1	w
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-65~150	°C



ELECTRICAL CHARACTERISTICS (Ta=25°C)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
Collector-Base Breakdown Voltage	ВV _{сво}	l _c =−100μA, l _E =0	-40			v
Collector-Emitter Breakdown Voltage	BVCEO	$l_{c} = -2mA$, $l_{B} = 0$	-25			v
Emitter-Base Breakdown Voltage	BV EBO	$l_{\rm E} = -100 \mu A$, $l_{\rm C} = 0$	-6			V
Collector Cutoff Current	I _{CBO}	$V_{CB} = -35V$, $I_F = 0$			-100	nA
Emitter Cutoff Current	I _{EBO}	$V_{EB} = -6V, I_{C} = 0$			-100	nA
DC Current Gain	h _{FE} 1	$v_{ce} = -1v$, $I_c = -5mA$	45	170		
	h _{FE} 2	$V_{ce} = -1V$, $I_c = -100mA$	85	160	300	
	h _{FF} 3	$V_{ce} = -1V$, $I_c = -800mA$	40	80		
Collector-Emitter Saturation Voltage	V _{CE} (sat)	$I_{c} = -800 \text{mA}, I_{B} = -80 \text{mA}$		-0.28	-0.5	V
Base-Emitter Saturation Voltage	V _{BE} (sat)	$I_c = -800 \text{mA}, I_B = -80 \text{mA}$		-0.98	-1.2	v
Base Emitter Voltage	V _{BE}	$V_{CE} = -1V$. $I_{C} = -10mA$		-0.66	-1.0	v
Output Capacitance	Cob	$V_{CB} = -10V. I_E = 0$		15		ρF
		t= i MHz				
Current Gain-Bandwidth Product	fT	$V_{CE} = -10V, I_C = -50mA$	100	200		MHz

h_{FE} (2) CLASSIFICATION

Classification	В	с	D
h _{FE} (2)	85-160	120-200	160-300



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